## SUPPLEMENTAL MATERIALS

This Supplemental Materials contains additional information about the charge current beyond the linear response theory and connections between the full fledged calculations performed using Kedlysh out-of-equilibrium approach and the results derived by means of the transport integrals method.

### I. ELECTRIC CURRENT BEYOND THE LINEAR RESPONSE

## A. Coupling asymmetry

If the quantum impurity is coupled to the leads with arbitrary coupling, the new variables (a and b) entering the FL Hamiltonian (6) [S1] are defined by Glazman-Raikh rotation [S2–S4] as follows:

$$\begin{pmatrix} b_{kr} \\ a_{kr} \end{pmatrix} = \begin{pmatrix} \cos\theta & \sin\theta \\ \sin\theta & -\cos\theta \end{pmatrix} \begin{pmatrix} c_{Lkr} \\ c_{Rkr} \end{pmatrix},$$
(S1)

where  $\tan\theta = |t_R/t_L|$  is given by the ratio of tunnel lead-dot matrix elements [S4] of the Hamiltonian (3). The symmetric coupling corresponds to  $\theta = \pi/4$ . We introduce the parameter  $C = \cos 2\theta = (\Gamma_L - \Gamma_R)/(\Gamma_L + \Gamma_R)$  to characterize the asymmetry of the dot-lead coupling;  $\Gamma_{\alpha} = \pi \nu N |t_{\alpha}|^2$  is intrinsic total local level width associated with the tunneling from/to the reservoirs (we assume that tunnel matrix elements are the same for all orbitals/flavours).

#### B. Phase shift

The phase shift expression in the presence of the finite voltage bias  $e\Delta V$ , finite temperature drop across the impurity  $\Delta T$  is given by the equation [S5]:

$$\delta(\varepsilon) = \delta_0 + \alpha_1 \varepsilon + \alpha_2 \varepsilon^2 - \frac{N-1}{4} \phi_2 \times \mathcal{A}, \tag{S2}$$

where

$$\mathcal{A} = \frac{1}{6} \left[ (\pi T_L)^2 (1 + \mathcal{C}) + (\pi T_R)^2 (1 - \mathcal{C}) + \frac{3}{2} (1 - \mathcal{C}^2) (e\Delta V)^2 \right].$$
 (S3)

The FL identities  $\alpha_1 = (N-1)\phi_1$  and  $\alpha_2 = 1/4(N-1)\phi_2$  follow from the Kondo floating paradigm [S5–S7]. The exact relation between  $\alpha_1$  and  $\alpha_2$  is given by the Bethe-Ansatz solution [S5, S7]:

$$\frac{\alpha_2}{\alpha_1^2} = \frac{N-2}{N-1} \frac{\Gamma(1/N) \tan(\pi/N)}{\sqrt{\pi} \Gamma\left(\frac{1}{2} + \frac{1}{N}\right)} \cot \delta_0.$$
(S4)

Here  $\Gamma(x)$  is the Euler's gamma-function.

### C. Elastic current

The elastic contribution to the charge current is performed by averaging the current with  $H_{\alpha}$  of (6) which is equivalent to use of the Landauer-Büttiker formula [S8] containing the energy dependent transmission coefficient  $\mathcal{T}(\varepsilon)$  computed with the scattering phase (S2, S3):

$$I_{el} = \frac{Ne}{h} \int d\varepsilon \mathcal{T}(\varepsilon) \Delta f(\varepsilon), \quad \mathcal{T}(\varepsilon) = (1 - \mathcal{C}^2) \sin^2[\delta(\varepsilon)].$$
(S5)

Computing integrals with Fermi distribution function we obtain the elastic current:

$$I_{el} = \frac{Ne}{h} \left( 1 - \mathcal{C}^2 \right) \left[ \left( \mathcal{T}_0 - \sin 2\delta_0 \alpha_2 \mathcal{A} \right) \mathcal{J}_0 - \sin 2\delta_0 \alpha_1 \mathcal{J}_1 + \left( \cos 2\delta_0 \alpha_1^2 + \sin 2\delta_0 \alpha_2 \right) \mathcal{J}_2 \right],$$
(S6)

where we use short-hand notations:

$$\mathcal{J}_{0} = e\Delta V, \quad \mathcal{J}_{1} = \frac{1}{6} \left[ (\pi T_{L})^{2} - (\pi T_{R})^{2} - 3(e\Delta V)^{2} \mathcal{C} \right],$$
  
$$\mathcal{J}_{2} = \frac{e\Delta V}{6} \left[ (\pi T_{L})^{2} (1 - \mathcal{C}) + (\pi T_{R})^{2} (1 + \mathcal{C}) + \frac{1}{2} (e\Delta V)^{2} (1 + 3\mathcal{C}^{2}) \right].$$
(S7)

#### D. Inelastic current

For computing the inelastic contribution to the current we use the general equation for the self-energies

$$\Sigma^{\eta_1,\eta_2}(t) = \left(\frac{\phi_1}{\pi\nu^2}\right)^2 \sum_{k_1,k_2,k_3} G^{\eta_1,\eta_2}_{bb}(k_1,t) G^{\eta_2,\eta_1}_{bb}(k_2,-t) G^{\eta_1,\eta_2}_{bb}(k_3,t)$$
(S8)

expressed in terms of the fermionic Green's functions (which replace (12) in [S1]):

$$G_{bb}^{+-}(t) = -\frac{\pi\nu}{2} \left[ \frac{T_L(1+\mathcal{C})e^{-i\mu_L t}}{\sinh(\pi T_L t)} + \frac{T_R(1-\mathcal{C})e^{-i\mu_R t}}{\sinh(\pi T_R t)} \right],$$
(S9)

$$G_{ab/ba}(t) = -\frac{\pi\nu}{2}\sin 2\theta \left[\frac{T_L e^{-i\mu_L t}}{\sinh(\pi T_L t)} - \frac{T_R e^{-i\mu_R t}}{\sinh(\pi T_R t)}\right],\tag{S10}$$

where  $\mu_L = \frac{e\Delta V}{2}(1-\mathcal{C})$  and  $\mu_R = -\frac{e\Delta V}{2}(1+\mathcal{C})$ . We also take into account the coefficient  $\sin 2\theta$  in front of the definition of the total current in Eq. 6 and  $\sin^2 2\theta$  in front of the inelastic current in Eq. 11 in [S1].

The inelastic current for symmetrical dot-lead coupling is given by the relation:

$$\delta I_{in} = \frac{N(N-1)e\pi}{2h} \left(\frac{\phi_1}{\pi\nu^2}\right)^2 2\cos 2\delta_0 \left(\frac{\pi\nu}{2}\right)^4 \times \left\{ \left[\mathcal{L}(T_L, T_R, z) - \mathcal{L}(T_L, T_R, 0)\right] - \left[\mathcal{L}(T_R, T_L, -z) - \mathcal{L}(T_R, T_L, 0)\right] \right\},\tag{S11}$$

where

$$\mathcal{L}(x,y,z) = \int_{-\infty-i\gamma}^{+\infty-i\gamma} \left[ x^4 \frac{e^{-izt} + e^{2izt}}{\sinh^4(\pi xt)} + x^3 y \frac{3 + 2e^{izt} - e^{-2izt}}{\sinh^3(\pi xt)\sinh(\pi yt)} + \frac{3}{2} x^2 y^2 \frac{e^{izt} - e^{-izt}}{\sinh^2(\pi xt)\sinh^2(\pi yt)} \right] dt,$$
(S12)

Here we denoted  $z=e\Delta V$  and introduced the point splitting parameter  $\gamma$  [S5, S9] to regularize the integrals (S12) divergent at t=0. The parameter  $\gamma$  is chosen to satisfy the conditions  $\gamma e\Delta V \ll 1$ ,  $\gamma T \ll 1$  and  $T_K/D \ll \gamma T_K \ll 1$  [S5] (*D* is a bandwidth of conduction band,  $T \ll T_K$ ,  $T_K/D \propto \sqrt{(\Gamma_L + \Gamma_R)/D} \exp[-c \cdot U/(\Gamma_L + \Gamma_R)]$ ,  $c \sim 1$ ). We show on Fig. S1 the thermo-voltage  $\Delta V$  as a function of two temperatures  $T_L$  and  $T_R$  of the left-right leads

We show on Fig. S1 the thermo-voltage  $\Delta V$  as a function of two temperatures  $T_L$  and  $T_R$  of the left-right leads for three important cases discussed in the paper: i) m = 1 SU(2); ii) m = 1 SU(4) and iii) m = 2 SU(4). One can see similarity of the plots i) and iii) describing the broken by potential scattering particle-hole symmetric regimes. The density plot visualises the non-linearity of the thermo-voltage at low compared to  $T_K$  temperatures.

# **II. TRANSPORT INTEGRALS**

We illustrate the application of the textbook [S10, S11] method of transport integrals to the thermoelectric transport through the SU(N) quantum impurity assuming the symmetric dot-leads coupling for simplicity. The



FIG. S1. (Color online) Density plot showing the thermo-voltage  $e\Delta V/T_K$  obtained at the zero-current conditions as a function of the temperatures of L/R contacts. Left panel: SU(2) PH-symmetric Kondo regime m = 1; central panel: SU(4) PH-non-symmetric Kondo regime m = 1; right panel: SU(4) PH-symmetric Kondo regime m = 2; for all plots:  $\delta_P = 0.3$ ,  $\gamma T_K = 0.001$  and  $\mathcal{C} = 0$ .

charge and the heat currents in the linear response theory are connected by equations:

$$\begin{pmatrix} I_{charge} \\ I_{heat} \end{pmatrix} = \begin{pmatrix} L_{11} & L_{12} \\ L_{21} & L_{22} \end{pmatrix} \begin{pmatrix} \Delta V \\ \Delta T \end{pmatrix}.$$
(S13)

Differential conductance G(T) and differential thermopower S(T) are defined as follows:

$$G(T) = \lim_{\Delta V \to 0} \left. \frac{I_{charge}}{\Delta V} \right|_{\Delta T=0} = L_{11}, \tag{S14}$$

$$S(T) = -\lim_{\Delta T \to 0} \left. \frac{\Delta V}{\Delta T} \right|_{I_{charge} = 0} = L_{12}/L_{11}.$$
(S15)

The coefficients  $L_{ij}$  are expressed in terms of the transport integrals (see e.g. [S11] for details of the derivation):

$$\mathcal{I}_n(T) = \frac{1}{h} \sum_{\sigma} \int d\varepsilon \cdot \varepsilon^n \left( -\frac{\partial f}{\partial \varepsilon} \right) \cdot \operatorname{Im} \left[ -\pi \nu T_{\sigma}(\varepsilon) \right].$$
(S16)

Here  $L_{11} = e^2 \mathcal{I}_0$ ,  $L_{12} = -e \mathcal{I}_1/(2T)$  and  $T_{\sigma}$  is a diagonal part of a single-particle T-matrix defined by the Dyson equation [S4]:

$$\mathcal{G}_{\sigma k}(\varepsilon) = \mathcal{G}_{\sigma k}^{0}(\varepsilon) + \mathcal{G}_{\sigma k}^{0}(\varepsilon) T_{\sigma}(\varepsilon) \mathcal{G}_{\sigma k}^{0}(\varepsilon), \qquad (S17)$$

where  $\mathcal{G}^0_{\sigma k}(\varepsilon)$  and  $\mathcal{G}_{\sigma k}(\varepsilon)$  are bare and full electron Green's functions.

The full T-matrix consists of the elastic part

$$T_{\sigma}^{el}(\varepsilon) = -\frac{i}{2\pi\nu} \left(1 - e^{2i\delta_{\sigma}(\varepsilon)}\right),\tag{S18}$$

and the inelastic part

$$T_{\sigma}^{in}(\varepsilon) = -\frac{i}{2\pi\nu} (N-1)e^{2i\delta_0}\phi_1^2 \left[\varepsilon^2 + (\pi T)^2\right].$$
 (S19)

Here we used the FL Hamiltonian (6) of [S1] describing the SU(N) Kondo model at the strong coupling fixed point. We compute the transport integrals by Taylor-expanding the T-matrix

$$-\pi\nu \text{Im}T_{\sigma}(\varepsilon) = \mathcal{A}_1 + \mathcal{A}_2\varepsilon + \mathcal{A}_3\varepsilon^2 + \dots$$
(S20)

where the coefficients  $\mathcal{A}_1$ ,  $\mathcal{A}_2$  and  $\mathcal{A}_3$  are defined as follows:

$$\mathcal{A}_{1} = \left[ \mathcal{T}_{0} + \frac{(\pi T)^{2} (N-1)}{2} \left( \phi_{1}^{2} \cos 2\delta_{0} - \sin 2\delta_{0} \frac{\phi_{2}}{6} \right) \right],$$
(S21)

$$\mathcal{A}_2 = \alpha_1 \sin 2\delta_0, \tag{S22}$$

$$\mathcal{A}_3 = \left\lfloor \cos 2\delta_0 \left( \alpha_1^2 + \frac{(N-1)\phi_1^2}{2} \right) + \sin 2\delta_0 \alpha_2 \right\rfloor.$$
(S23)

The transport integrals for n = 0, 1, 2 are given by equations:

$$\mathcal{I}_{0} = \frac{N}{h} \left[ \mathcal{A}_{1} + \frac{\mathcal{A}_{3}}{3} (\pi T)^{2} \right], \qquad \mathcal{I}_{1} = \frac{N \mathcal{A}_{2}}{3h} (\pi T)^{2}, \qquad \mathcal{I}_{2} = \frac{N}{h} \left[ \frac{\mathcal{A}_{1}}{3} (\pi T)^{2} + \frac{7 \mathcal{A}_{3}}{15} (\pi T)^{4} \right].$$
(S24)

The transport coefficients: the electrical conductance G(T), thermopower S(T) and thermal conductance  $K_e(T)$  read as:

$$G = e^2 \mathcal{I}_0, \quad S = -\frac{1}{eT} \frac{\mathcal{I}_1}{\mathcal{I}_0}, \quad K_e = \frac{1}{T} \left[ \mathcal{I}_2 - \frac{\mathcal{I}_1^2}{\mathcal{I}_0} \right].$$
 (S25)

The electronic contribution to the thermoelectric figure of merit ZT and the normalized power factor PF are expressed in terms of thermoelectric properties defined in Eq.(S25) via  $ZT = S^2 GT/K_e$  and  $PF = S^2 G/G_0$ .

- [S1] D.B. Karki and M. N. Kiselev, main text
- [S2] L. I. Glazman and M. E. Raikh, J. Exp. Theor. Phys. 27, 452 (1988).
- [S3] T. K. Ng and P. A. Lee, Phys. Rev. Lett. 61, 1768 (1988).
- [S4] M. Pustilnik and L. Glazman, J. Phys.: Condens. Matter 16, R513 (2004).
- [S5] C. Mora, P. Vitushinsky, X. Leyronas, A. A. Clerk, and K. L. Hur, Phys. Rev. B 80, 155322 (2009).
- [S6] P. Noziéres, J. Low Temp. Phys. 17 (1974).
- [S7] C. Mora, Phys. Rev. B 80, 125304 (2009).
- [S8] Y. M. Blanter and Y. V. Nazarov, *Quantum Transport: Introduction to Nanoscience* (Cambridge University Press, Cambridge, 2009).
- [S9] I. Affleck and A. W. W. Ludwig, Phys. Rev. B 48, 7297 (1993).
- [S10] V. Zlatic and R. Monnier, Modern Theory of Thermoelectricity (Oxford University Press, 2014).
- [S11] T. A. Costi and V. Zlatić, Phys. Rev. B 81, 235127 (2010).